

SEMICONDUCTOR TM

KSC2690/2690A

Audio Frequency High Frequency Power Amplifier Complement to KSA1220/KSA1220A



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage		
	: KSC2690	120	V
	: KSC2690A	160	V
V _{CEO}	Collector- Emitter Voltage		
	: KSC2690	120	V
	: KSC2690A	160	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current (DC)	1.2	А
I _{CP}	*Collector Current (Pulse)	2.5	А
I _B	Base Current(DC)	0.3	А
P _C	Collector Dissipation (T _a =25°C)	1.2	W
P _C P _C	Collector Dissipation (T _C =25°C)	20	W
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 55 ~ 150	°C

Electrical Characteristics T_C=25°C unless otherwise noted

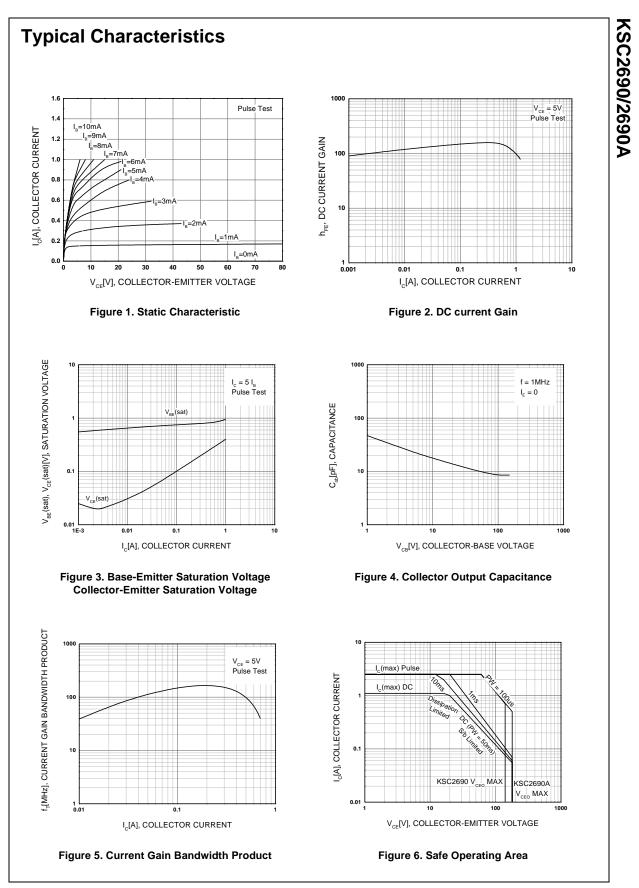
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I _{CBO}	Collector Cut-off Current	V _{CB} = 120V, I _E = 0			1	μΑ
I _{EBO}	Emitter Cut-off Current	V _{EB} = 3V, I _C = 0			1	μΑ
h _{FE1}	* DC Current Gain	$V_{CE} = 5V, I_{C} = 5mA$	35	105		
h _{FE2}		$V_{CE} = 5V, I_{C} = 0.3A$	60	140	320	
V _{CE} (sat)	* Collector-Emitter Saturation Voltage	I _C = 1A, I _B = 0.2A		0.4	0.7	V
V _{BE} (sat)	* Base-Emitter Saturation Voltage	I _C = 1A, I _B = 0.2A		1	1.3	V
f _T	Current Gain Bandwidth Product	$V_{CE} = 5V, I_{C} = 0.2A$		155		MHz
C _{ob}	Output Capacitance	V _{CB} =10V, I _E =0, f = 1MHz		19		pF

* Pulse Test: PW≤350µs, Duty Cycle≤2% Pulsed

h_{FE} Classificntion

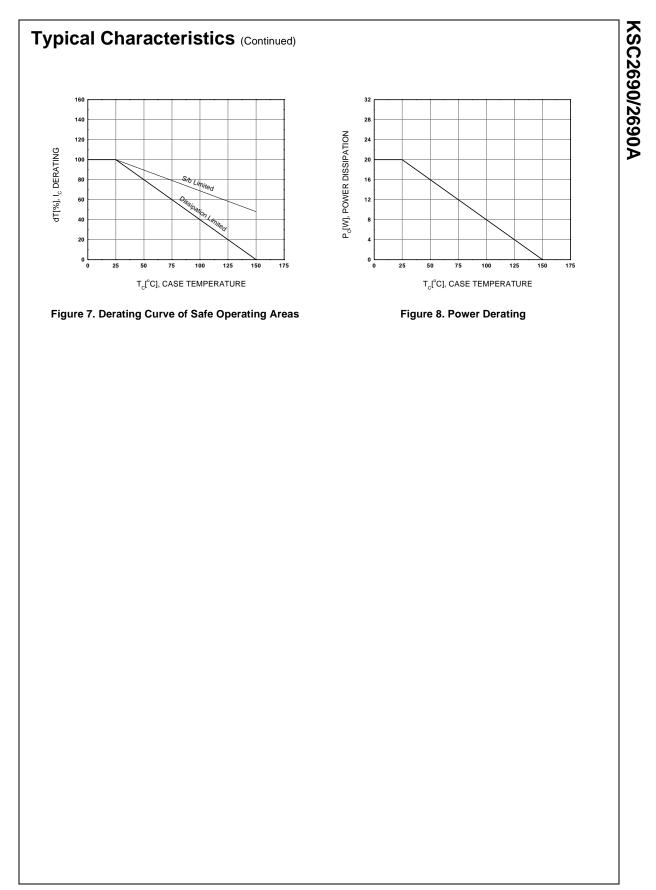
Classification	R	0	Y
h _{FE2}	60 ~ 120	100 ~ 200	160 ~ 320

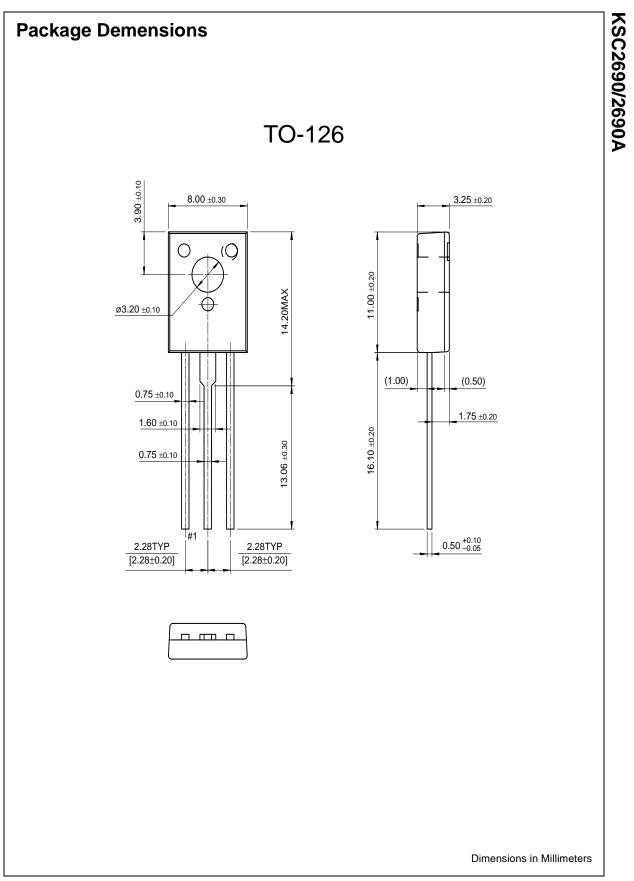
Rev. A, February 2000



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PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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Product status/pricing/packaging

Product	Product status	Pricing*	Package type	Leads	Packing method
KSC2690AYS	Full Production	\$0.22	<u>TO-126</u>	3	BULK
KSC2690AOS	Full Production	\$0.22	<u>TO-126</u>	3	BULK
KSC2690AOSTSTU	Full Production	\$0.22	<u>TO-126</u>	3	RAIL
KSC2690AYSTSTU	Full Production	\$0.22	<u>TO-126</u>	3	RAIL
KSC2690AYSTU	Full Production	\$0.22	<u>TO-126</u>	3	RAIL

* 1,000 piece Budgetary Pricing

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Models

Package & leads Condition Temperature range Software version Re	ate
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PSPICE							
TO-126-3	Electrical/Thermal	-25°C to 100°C	9	Mar 30, 2000			

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